

S34ML02G200BHA000

S34ML02G200BHA000 Information

Western Barrier and Bar	 S34ML02G200BHA000 Cypress Semiconductor Corp Integrated Circuits (ICs) Memory NAND - For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



S34ML02G200BHA000 Specifications

Manufacturer Part Number	S34ML02G200BHA000
Manufacturer	Cypress Semiconductor Corp
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	Automotive, AEC-Q100, ML-2
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	2Gb (256M x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	25ns
Access Time	-
Voltage - Supply	2.7 V ~ 3.6 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

S34ML02G200BHA000 Guarantees



Quality Guarantees

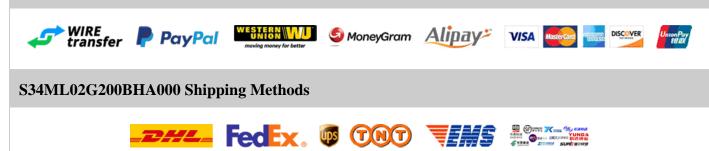
We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

S34ML02G200BHA000 Payment Methods



If you have any question about S34ML02G200BHA000, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com